

Semester S1 –Basics of active and non linear electronics

RF Power amplifiers (JM Nebus)

TUTORIAL N° 6

Let us consider the Doherty equivalent circuit at the fundamental frequency represented in figure 1 :

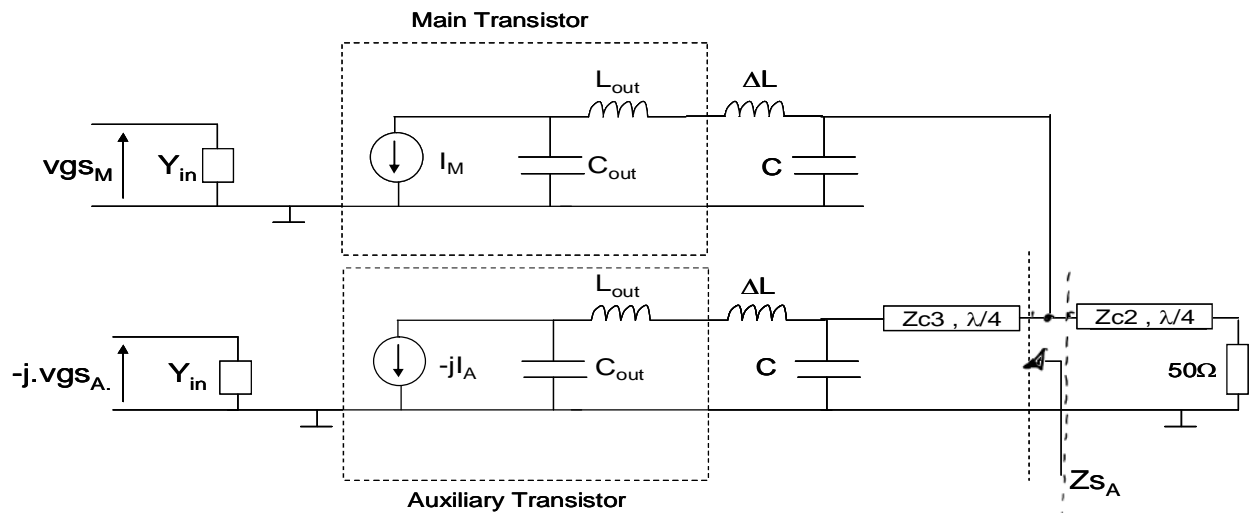


Figure 1

$$R_L = \frac{R_{opt}}{2} = 14 \Omega$$

The variations of the drain currents I_M and I_A versus V_{gs} are similar to the those given in the course .

The operating frequency is 4 Ghz

Transistor's parameters are the following

$$I_{dss} = 1,2 \text{ A} , V_{ds0} = 20 \text{ V} , V_{dsmin} = V_k = 3 \text{ V}$$

$$C_{out} = 1,4 \text{ pF} \text{ et } L_{out} = 0,7 \text{ nH}$$

- 1) Determine the values of R_{opt} and $2R_{opt}$ for a suitable Doherty load modulation operation

$$\begin{cases} 1 - LC\omega^2 = 0 \\ \text{AND} \\ jC\omega = \frac{j}{Z_C} \end{cases}$$

$$\rightarrow jL\omega = jZ_C$$

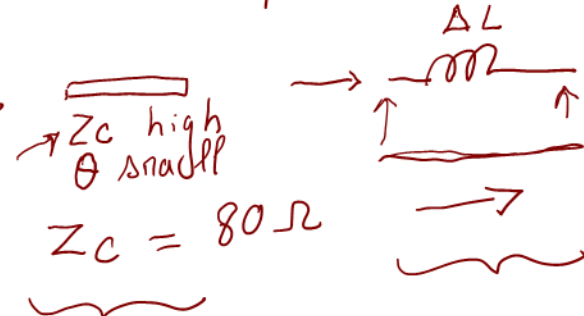
$$\rightarrow Z_C = \frac{1}{C\omega} \quad ?? \quad \frac{1}{1.4 \cdot 10^{-12} \times 2\pi \times 4 \cdot 10^9} = \boxed{28 \Omega}$$

$$\rightarrow LC\omega^2 = 1$$

$$L = \frac{1}{1.4 \cdot 10^{-12} \times 4\pi^2 \cdot 4^2 \cdot 10^{18}} = 1.13 \text{ mH}$$

$$\Delta L = 1.13 - 0.7 = 0.43 \text{ mH}$$

$$C = C_{out} = 1.4 \text{ pF}$$

5) \rightarrow 

$$\begin{aligned} \cos \theta &\approx 1 \\ \sin \theta &\approx \theta \end{aligned}$$

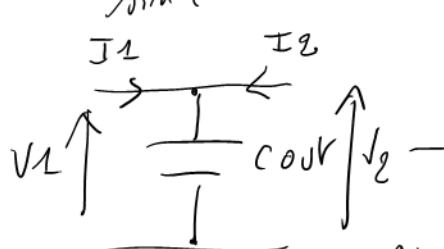
$$\begin{pmatrix} \cos \theta & jZ_C \sin \theta \\ j \frac{\sin \theta}{Z_C} & \cos \theta \end{pmatrix} = \begin{pmatrix} 1 & jL\omega \\ 0 & 1 \end{pmatrix}$$

$$\begin{pmatrix} 1 & jZ_C \theta \\ 0 & 1 \end{pmatrix} = \begin{pmatrix} 1 & jL\omega \\ 0 & 1 \end{pmatrix}$$

$$\begin{aligned} L\omega &= Z_C \theta \\ \theta &= \frac{L\omega}{Z_C} \end{aligned}$$

For example
we choose $Z_C = 80 \Omega$
 $\rightarrow \theta = 0.135 \text{ rad}$
 $\theta = 7.8^\circ$

$$\begin{aligned} \cos(0.135) &= 0.99 \approx 1 \\ \sin(0.135) &= 0.134 \end{aligned}$$

 $\rightarrow \begin{pmatrix} 1 & 0 \\ jC\omega & 1 \end{pmatrix} = \begin{pmatrix} \cos \theta & jZ_C \sin \theta \\ j \frac{\sin \theta}{Z_C} & \cos \theta \end{pmatrix} \rightarrow \approx 0$

$$C_{out} = \frac{\theta}{Z_C \omega} \rightarrow (20^\circ) \quad \theta \text{ small} \rightarrow \cos \theta = 1$$

$\theta = 0.35 \text{ rad}$ $Z_C \text{ small.}$ For example $Z_C = 10 \Omega$

\hookrightarrow Verification: $\cos(0.352) = 0.94$ $\sin(0.352) = 0.342$



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Electronics and Optics Master

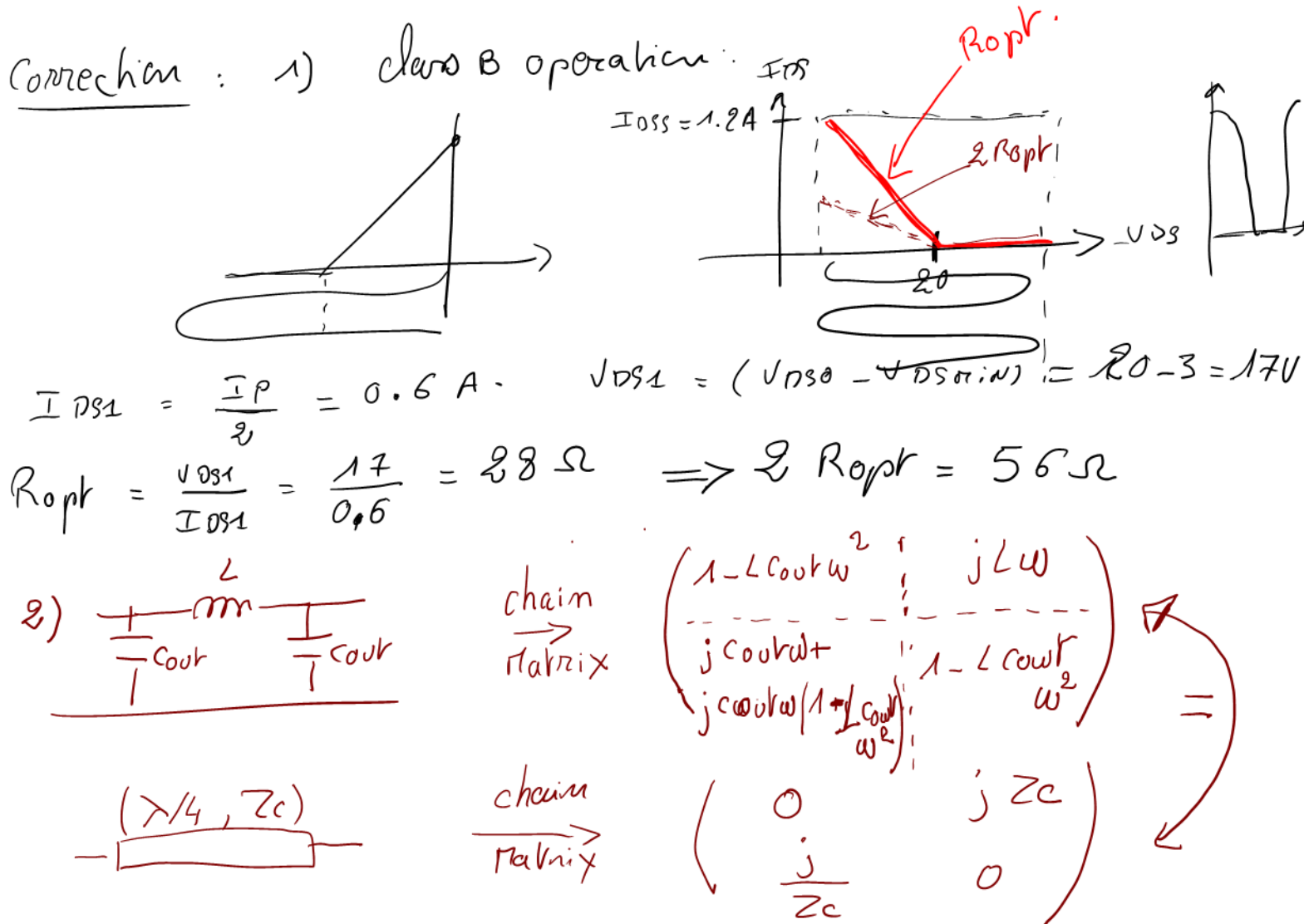


2) Determine the values of ΔL and C required to have an equivalent impedance inverting function ($\lambda/4$, $Z_{c1}=R_{opt}$) realized by the (C_{out} ; $L_{out} + \Delta L$; C) network connected at the output of drain current sources I_M and I_A .

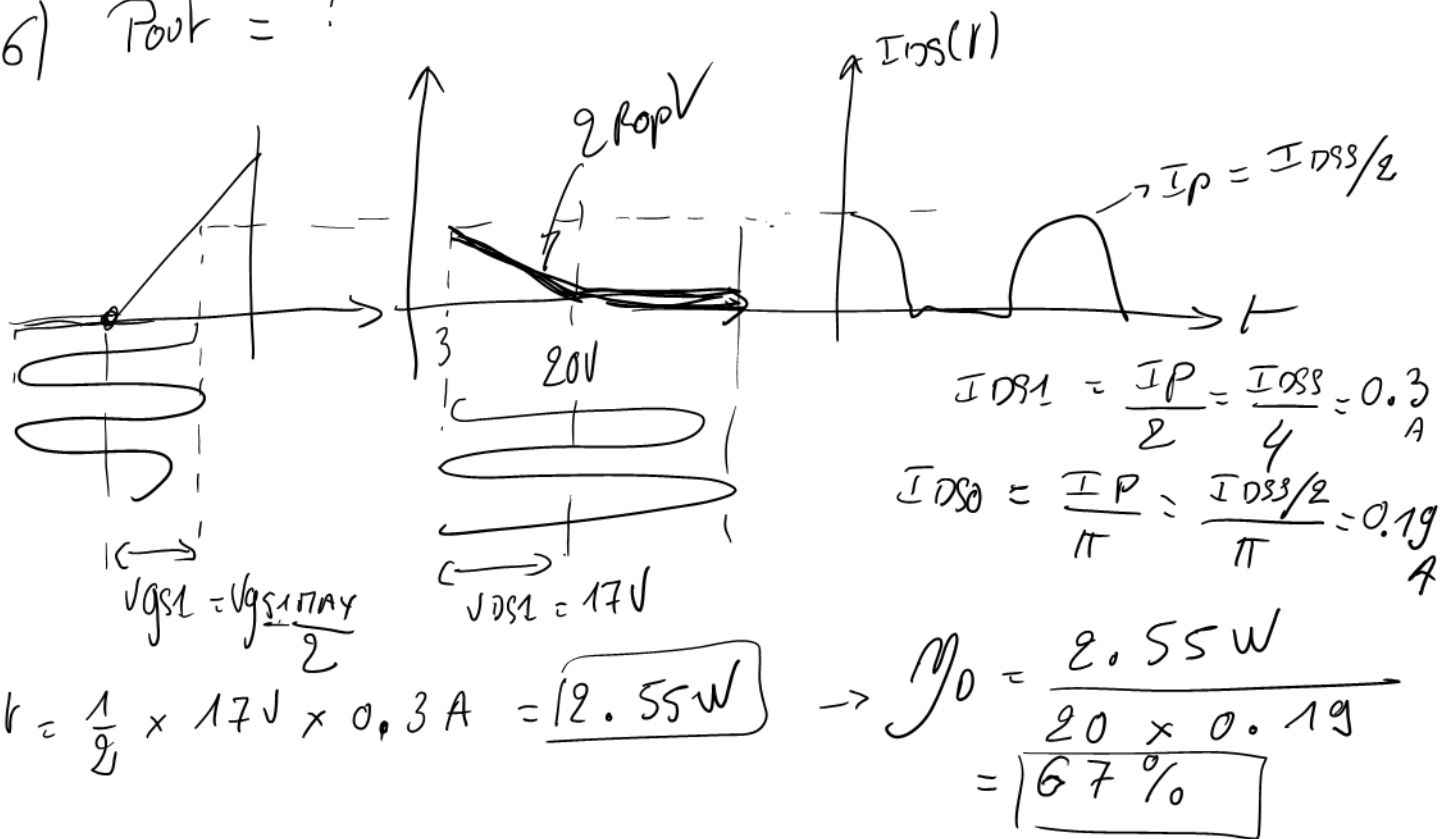
3) What is the value of Z_{c2} $\rightarrow R_L = 14 = \frac{Z_{c2}^2}{50} \Rightarrow Z_{c2} = 26.5 \Omega$

4) When the auxiliary transistor is OFF, what is the value of Z_{SA} impedance. $Z_{SA} = \infty$
open circuit

5) Propose a realisation of ΔL and C with distributed components



6) $P_{out} = ?$



7) $V_{gs1} = V_{gs1max}$ for both transistors.

$$P_H = \frac{1}{2} \times V_{ds1} I_{DSS1} = \frac{1}{2} \times 17 \times 0.6 = 5.1W$$

$$P_A = \frac{1}{2} \times V_{ds1} I_{DSS1} = \frac{1}{2} \times 17 \times 0.6 = 5.1W$$

$$P_{Amplifier} = 10.2W$$

$$P_{DC_Amplifier} = P_{DC_main} + P_{DC_Aux} = 20 \times \left(\frac{1.2}{\pi}\right) + 20 \times \left(\frac{1.2}{\pi}\right)$$

$$P_{DC} = 15.28W$$

$$\eta_D = \frac{10.2}{15.28} \approx 66.7\%$$

